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J. L. Blankenship

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James L. Blankenship

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SEMICONDUCTOR NUCLEAR RADIATION DETECTORS

INTRODUCTION

This bibliography is the outgrowth of a program initiated by the Basic Instrumentation Research Group of the Oak Ridge National Laboratory. The purpose of the program is to investigate the potential uses of semiconductors as nuclear radiation detectors. Most references on the uses of cadmium sulfide have been omitted, except for recent articles, because excellent bibliographies have already been prepared.

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